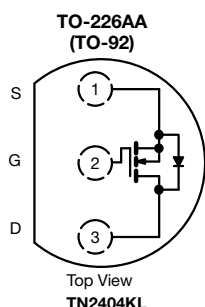


N-Channel 240 V (D-S) MOSFET

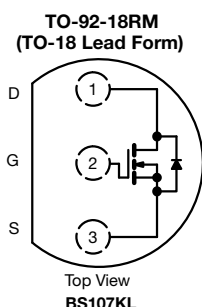
PRODUCT SUMMARY					
Part Number	V _{DS} (V)	R _{DS(on)} (Ω)	V _{GS(th)} (A)	I _D (A)	Q _g (Typ.)
TN2404K	240	4 at V _{GS} = 10 V	0.8 to 2	0.2	4.87 nC
TN2404K, BS107KL				0.3	



Device Marking Front View

"S" TN
2404KL
xxyy

"S" = Siliconix Logo
xxyy = Date Code



Device Marking Front View

"S" BS
107KL
xxyy

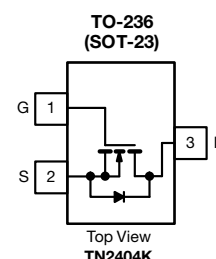
"S" = Siliconix Logo
xxyy = Date Code

FEATURES

- Low On-Resistance: 4 Ω
- Secondary Breakdown Free: 260 V
- Low Power/Voltage Driven
- Low Input and Output Leakage
- Excellent Thermal Stability
- Material categorization:
For definitions of compliance please see
www.vishay.com/doc?99912

APPLICATIONS

- High-Voltage Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Transistors, etc.
- Telephone Mute Switches, Ringer Circuits
- Power Supply, Converters
- Motor Control



BENEFITS

- Low Offset Voltage
- Full-Voltage Operation
- Easily Driven Without Buffer
- Low Error Voltage
- No High-Temperature "Run-Away"

Marking Code: K1ywl
K1 = Part Number Code for TN2404K
y = Year Code
w = Week Code
l = Lot Traceability

ORDRING INFORMATION

Standard Partnumber	Ordering Part Number	Option
TN2404K	TN2404K-T1-E3	Lead (Pb) free
	TN2404K-T1-GE3	Lead (Pb) free and Halogen free
TN2404KL	TN2404KL-TR1-E3	With Tape and Reel Spool Option
BS107KL	BS107KL-TR1-E3	

ABSOLUTE MAXIMUM RATINGS (T_A = 25 °C, unless otherwise noted)

Parameter		Symbol	TN2404K	TN2404KL/BS107KL	Symbol
Drain-Source Voltage		V _{DS}	240		V
Gate-Source Voltage		V _{GS}	± 20		
Continuous Drain Current (T _J = 150 °C)	T _A = 25 °C	I _D	0.2	0.3	A
	T _A = 70 °C		0.16	0.25	
Pulsed Drain Current (t = 300 μs)		I _{DM}	0.8	1.4	
Maximum Power Dissipation	T _A = 25 °C	P _D	0.36	0.8	W
	T _A = 70 °C		0.23	0.51	
Thermal Resistance Junction-to-Ambient		R _{thJA}	350 ^b	156	°C/W
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C

Notes:

a. Pulse width limited by maximum junction temperature.

b. Surface mounted on an FR4 board.

SPECIFICATIONS ($T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise noted)

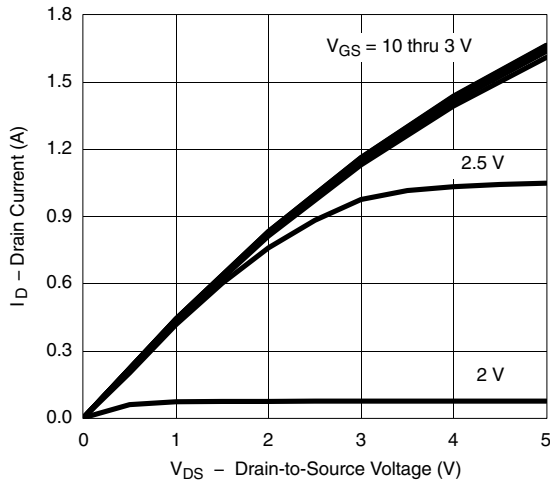
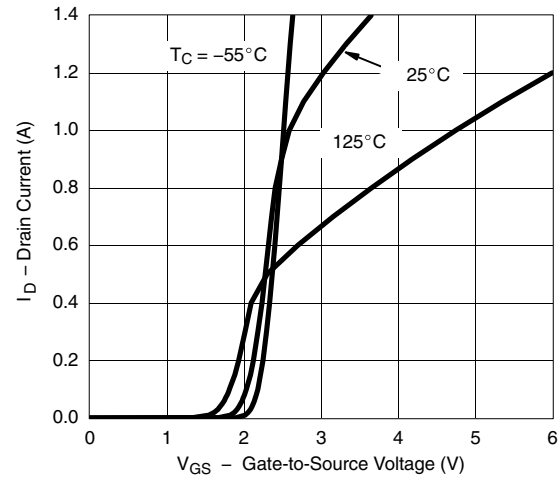
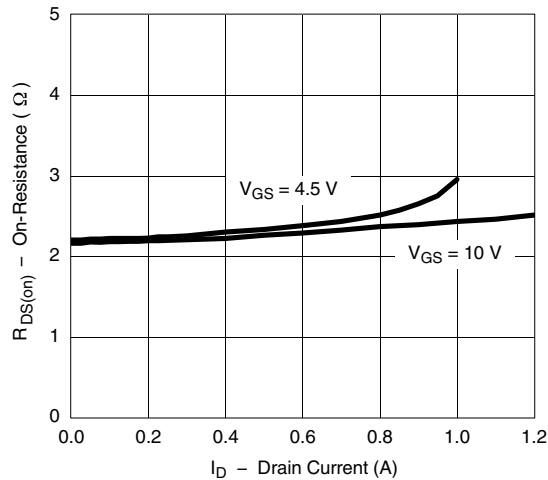
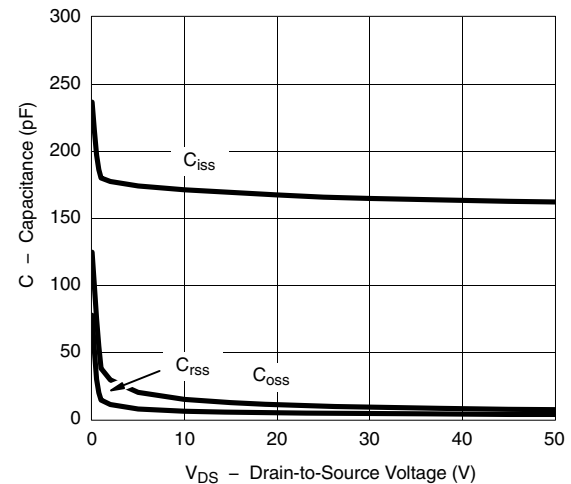
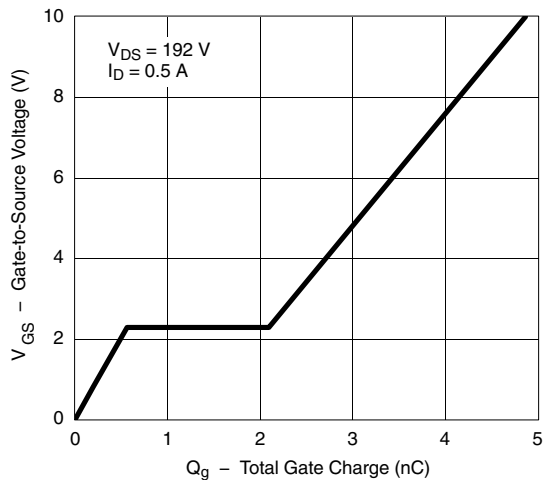
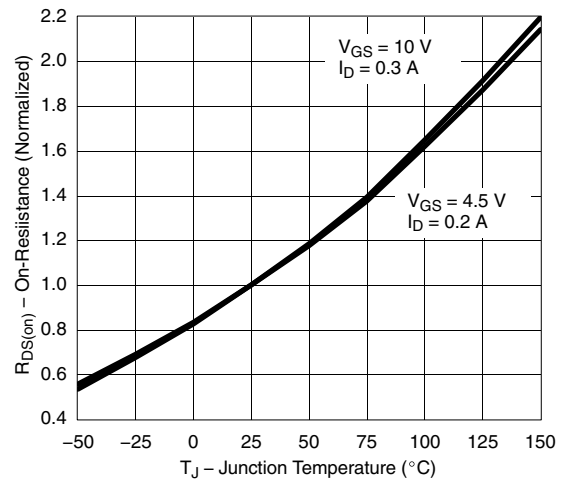
Parameter	Symbol	Test Conditions	Limits			
			Min.	Typ. ^a	Max.	Unit
Static						
Drain-Source Breakdown Voltage	V _{DS}	V _{GS} = 0 V, I _D = 100 μA	240	257		V
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = 250 μA	0.8	1.65	2	
Gate-Source Leakage	I _{GSS}	V _{DS} = 0 V, V _{GS} = ± 20 V			± 100	nA
Zero Gate Voltage Drain Current	I _{BSS}	V _{DS} = 192 V, V _{GS} = 0 V			1	μA
		V _{DS} = 192 V, V _{GS} = 0 V, T _J = 55 °C			10	
On-State Drain Current ^a	I _{D(on)}	V _{DS} = 10 V, V _{GS} = 10 V	0.8			A
		V _{DS} = 10 V, V _{GS} = 4.5 V	0.5			
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = 10 V, I _D = 0.3 A		2.2	4	Ω
		V _{GS} = 4.5 V, I _D = 0.2 A		2.3	4	
		V _{GS} = 2.5 V, I _D = 0.1 A		2.4	6	
Forward Transconductance ^a	g _{fs}	V _{DS} = 10 V, I _D = 0.3 A		1.6		S
Diode Forward Voltage	V _{SD}	V _{GS} = 0 V, I _S = 0.3 A		0.8	1.2	V
Dynamic ^b						
Total Gate Charge	Q _g	V _{DS} = 192 V, V _{GS} = 10 V, I _D = 0.5 A		4.87	8	nC
Gate-Source Charge	Q _{gs}			0.56		
Gate-Drain Charge	Q _{gd}			1.53		
Turn-On Delay Time	t _{d(on)}	V _{DD} = 60 V, R _L = 200 Ω I _D ≅ 0.3 A, V _{GEN} = 10 V, R _g = 25 Ω		5	10	ns
Rise Time	t _r			12	20	
Turn-Off Delay Time	t _{d(off)}			35	60	
Fall Time	t _f			16	25	

Notes:

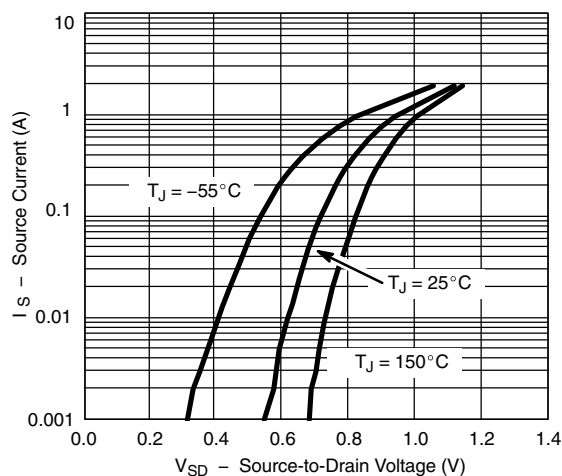
a. Pulse test; pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$

b. Guaranteed by design, not subject to production testing.

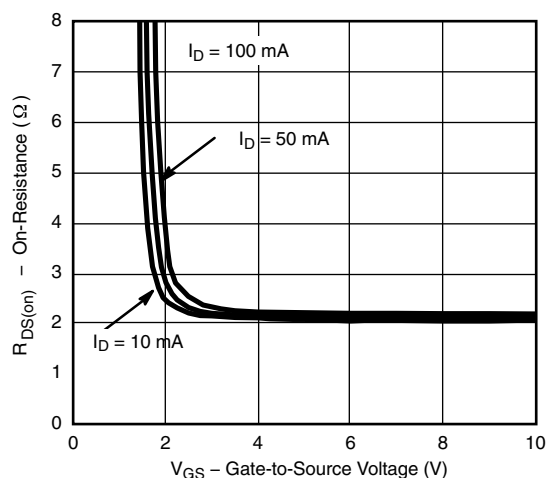
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

Output Characteristics

Transfer Characteristics

On-Resistance vs. Drain Current

Capacitance

Gate Charge

On-Resistance vs. Junction Temperature

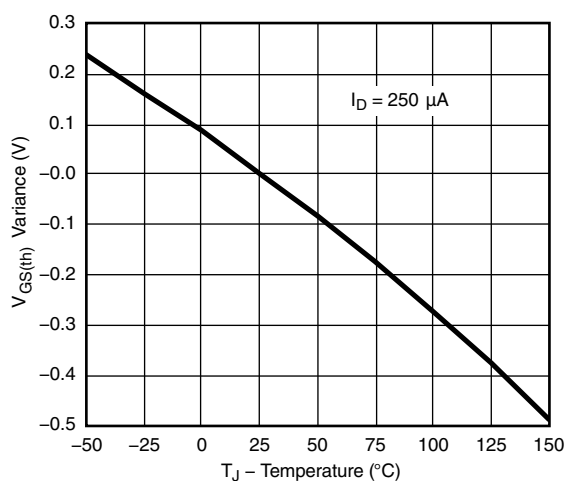
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



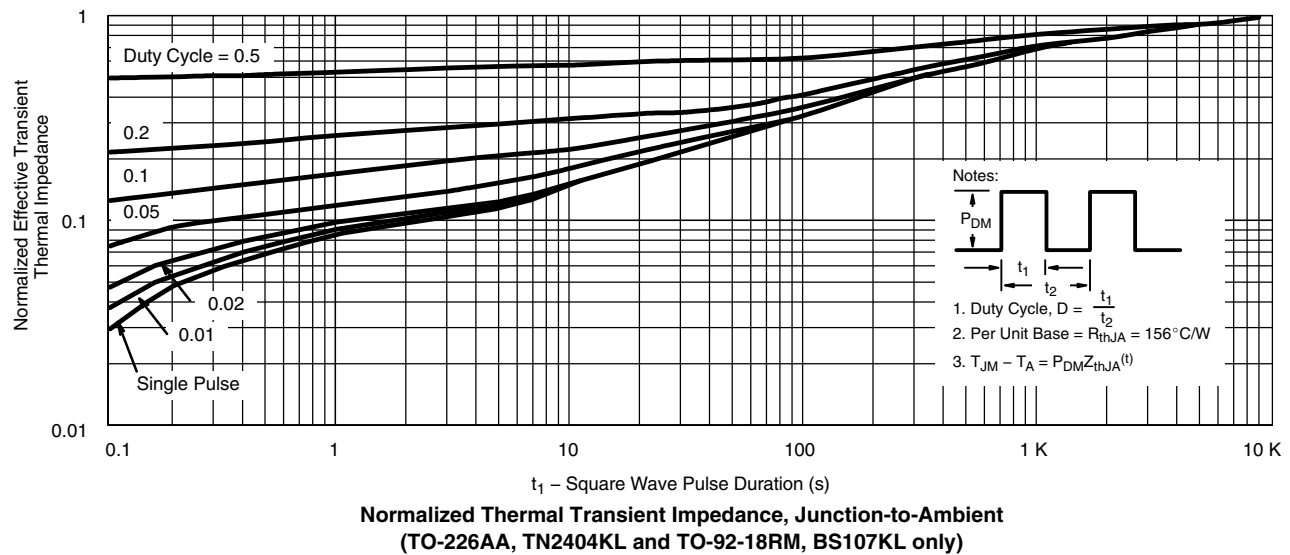
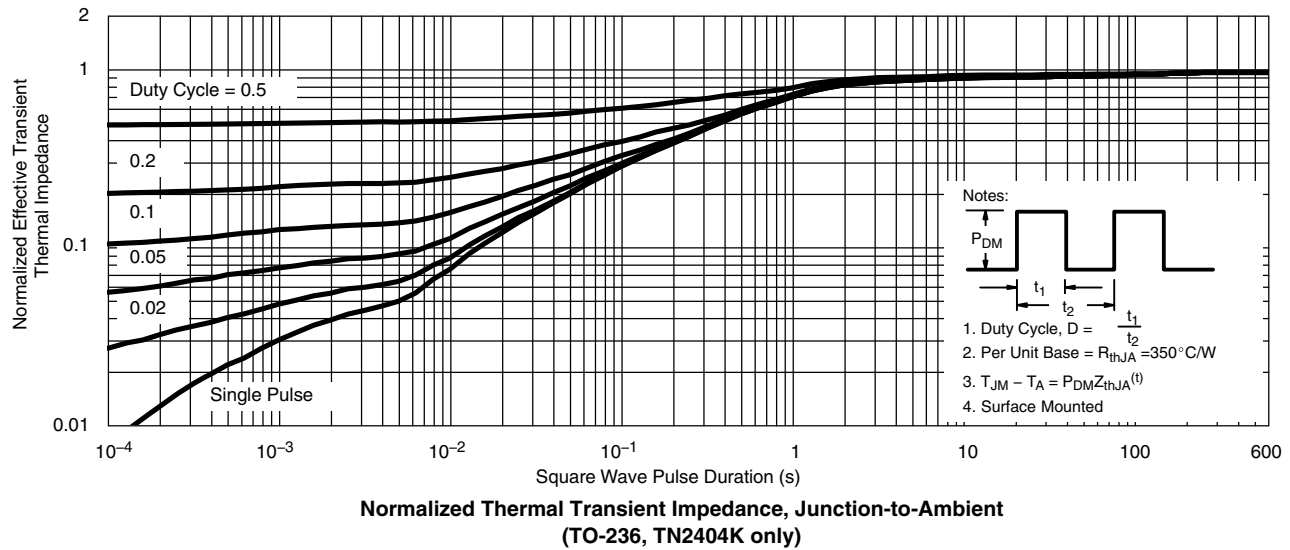
Source-Drain Diode Forward Voltage



On-Resistance vs. Gate-to-Source Voltage



Threshold Voltage

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)


Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?72225.

SOT-23 (TO-236): 3-LEAD



Dim	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	0.89	1.12	0.035	0.044
A ₁	0.01	0.10	0.0004	0.004
A ₂	0.88	1.02	0.0346	0.040
b	0.35	0.50	0.014	0.020
c	0.085	0.18	0.003	0.007
D	2.80	3.04	0.110	0.120
E	2.10	2.64	0.083	0.104
E ₁	1.20	1.40	0.047	0.055
e	0.95 BSC		0.0374 Ref	
e ₁	1.90 BSC		0.0748 Ref	
L	0.40	0.60	0.016	0.024
L ₁	0.64 Ref		0.025 Ref	
S	0.50 Ref		0.020 Ref	
q	3°	8°	3°	8°
ECN: S-03946-Rev. K, 09-Jul-01				
DWG: 5479				

RECOMMENDED MINIMUM PADS FOR SOT-23



Recommended Minimum Pads
Dimensions in Inches/(mm)

[Return to Index](#)



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